

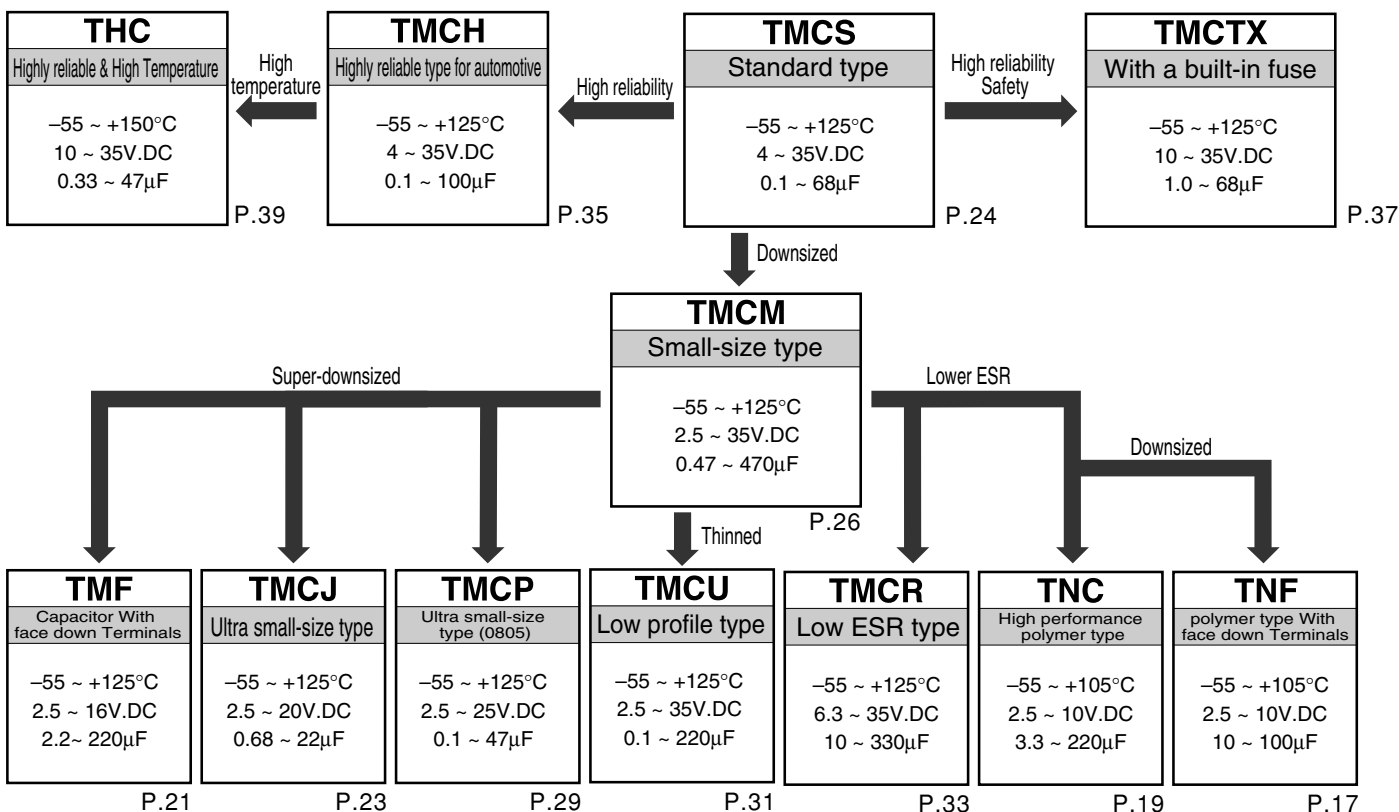
## Product Table

### List of tantalum electrolytic capacitor products

Series	Description	Operating temperature range	Standard type	Small-size type	Highly reliable type	Thin type	Low ESR type	Operating voltage V.DC	Capacitance range $\mu\text{F}$	See page:
TNF	Resin mold chip, polymer type with face down terminals	-55 ~ +105°C		○			○	2.5 ~ 10	10 ~ 100	17
TNC	Resin mold chip, high performance polymer type	-55 ~ +105°C					○	2.5 ~ 10	3.3 ~ 330	19
TMF	Resin mold chip, capacitor with face down terminals	-55 ~ +125°C		○				2.5 ~ 16	2.2 ~ 220	21
TM CJ	Resin mold chip, ultra small-size type (0603)	-55 ~ +125°C		○				2.5 ~ 20	0.68 ~ 22	23
TMCS	Resin mold chip, standard type	-55 ~ +125°C	○					4 ~ 35	0.1 ~ 68	24
TMCM	Resin mold chip, small-size type	-55 ~ +125°C		○				2.5 ~ 35	0.47 ~ 470	26
TMCP	Resin mold chip, ultra small-size type (0805)	-55 ~ +125°C		○				2.5 ~ 25	0.1 ~ 47	29
TM CU	Resin mold chip, low profile type	-55 ~ +125°C				○		2.5 ~ 35	0.1 ~ 220	31
TM CR	Resin mold chip, low ESR type	-55 ~ +125°C					○	6.3 ~ 35	10 ~ 330	33
TMCH	Resin mold chip, highly reliable type	-55 ~ +125°C			○			4 ~ 35	0.1 ~ 100	35
TMCTX	Resin mold chip, with a built-in fuse	-55 ~ +125°C			○			10 ~ 35	1.0 ~ 68	37
THC	Resin mold chip, high reliable, high temperature	-55 ~ +150°C			○			10 ~ 35	0.33 ~ 47	39

### Chip type

- VCR cameras, headphones, and other electronic equipment • Cameras • HIC • Automotive electrical equipment
- Personal computers • Cellular communications equipment • DC-DC converters • Others



Planning to change over to Sn100 plating for all series.

## Precautions in using Tantalum Capacitors

The major conditions to be considered in relation to the use of the tantalum capacitors are as follows:

- 1) Electrical conditions
- 2) Climatic conditions
- 3) Conditions for mounting on equipment and circuit boards
- 4) Mechanical vibration, shock, and storage conditions

If the tantalum capacitors are used without satisfying any one of these conditions, the probability of short-circuiting, leakage current increase or other problems to occur. To avoid such problems, observe the following precautions when using the tantalum capacitors.

### 1. Operating Voltage

- (1) The voltage derating factor should be as great as possible. Under normal conditions, the operating voltage should be reduced to 50% or less of the rated. It is recommended that the operating voltage be 30% or less of the rated, particularly when the tantalum capacitors are used in a low-impedance circuit (see Figs. 1, 2, and 3).
- (2) For circuits in which a switching, charging, discharging, or other momentary current flows, it is recommended that the operating voltage be 30% or less of the rated, with a resistor connected in series to limit the current to 300 mA or less (see section 4 for details).
- (3) When the tantalum capacitors are to be used at an ambient temperature of higher than 85°C, the recommended operating range shown in Fig. 3 should not be exceeded.

#### • Low-impedance circuits

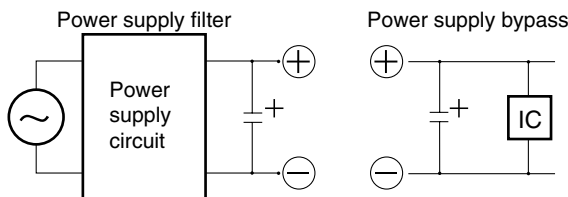


Fig. 1

Fig. 2

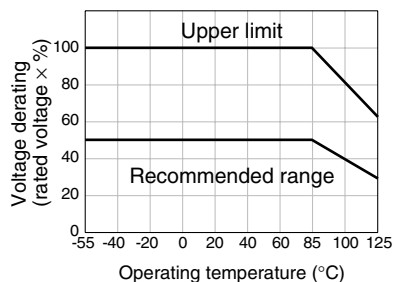


Fig. 3

## 2. Ripple

If an excessive ripple voltage is applied to the tantalum capacitors, their internal temperature rises due to Joule heat, resulting in the detriment of their reliability. The maximum permissible ripple voltage and current are related to the ratings or case size. Please consult us for detail information.

### 2.1 Ripple Current

The maximum permissible ripple current,  $I_{MAX}$ , is calculated as follows:

$$I_{MAX} = \sqrt{\frac{P_{MAX}}{ESR(D)}}$$

where:

$I_{MAX}$ : Maximum permissible capacitor ripple current (Arms).  
 $P_{MAX}$ : Maximum permissible capacitor power loss (W).  
 Varies with the ambient temperature and case size.  
 Calculated according to Table 1.

ESR (D): Capacitor equivalent series resistance ( $\Omega$ ).

Since the ESR(D) value varies with the ripple frequency, however, the following correction must be made in accordance with the operating frequency (see Table 2 and Fig. 4).

$$ESR(D) = K \cdot ESR(120)$$

K: Coefficient for the operating frequency (Table 2 and Fig. 4).

$$ESR(120) = \tan \delta \cdot X_c = \frac{\tan \delta}{2\pi f C}$$

where:

ESR (120): Equivalent series resistance at 120 Hz ( $\Omega$ ).

$X_c$ : Capacitive reactance at 120 Hz ( $\Omega$ ).

C: Electrostatic capacitance at 120 Hz ( $\mu F$ ).

f: Operating frequency (Hz).

Table 1 Maximum permissible power loss values ( $P_{MAX}$ ) by case size

Ambient temperature (°C)	$P_{MAX}$ (W)						
	LM,J	LP,P	LA,UA,A	UB,B	C	E	F
25	0.050	0.064	0.078	0.096	0.100	0.120	0.160
55	0.032	0.045	0.051	0.062	0.065	0.078	0.104
85	0.018	0.023	0.029	0.035	0.037	0.044	0.059

Table 2

Frequency f	K
120	1.0
400	0.8
1k	0.65
10k	0.50
20k	0.45
40k	0.43
100k	0.40
1M	0.35

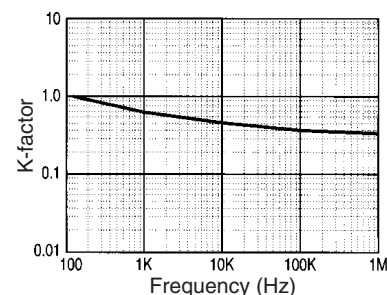


Fig. 4 Correction coefficient (K)

### 2.2 Ripple Voltage

- (1) The tantalum capacitors must be used in such a conditions that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage (Fig. 5)

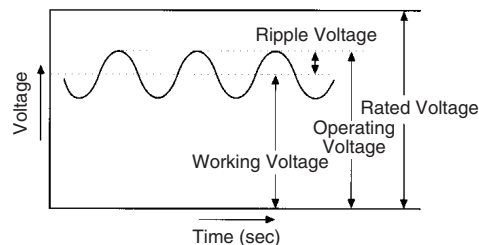


Fig. 5

- (2) Ensure that an reverse voltage due to superimposed voltages is not applied to the capacitors.
- (3) The maximum permissible ripple voltage varies with the rated voltage. Ensure that ripple voltage does not exceed the values shown in Figs. 6 and 7. If, however, the capacitors are used at a high temperature, the maximum permissible ripple voltage must be calculated as follows:

$$V_{rms} \text{ (at } 55^\circ\text{C)} = 0.8 \times V_{rms} \text{ (at } 25^\circ\text{C)}$$

$$V_{rms} \text{ (at } 85^\circ\text{C)} = 0.6 \times V_{rms} \text{ (at } 25^\circ\text{C)}$$

$$V_{rms} \text{ (at } 125^\circ\text{C)} = 0.4 \times V_{rms} \text{ (at } 25^\circ\text{C)}$$

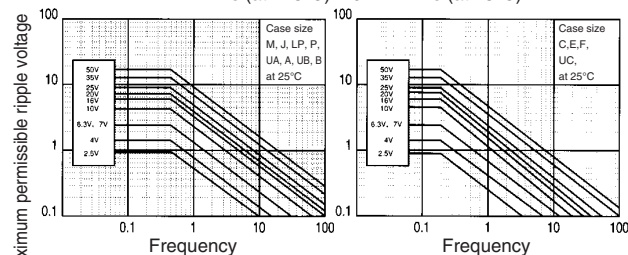


Fig. 6 Maximum permissible ripple voltage (LM, J, LP, P, UA, LA, A, UB, B)

Fig. 7 Maximum permissible ripple voltage (C, E, F)

## 3. Reverse Voltage

- (1) The tantalum capacitors must not be operated and charged in reverse mode. And also the capacitors must not be used in an pure AC circuit.
- (2) The tantalum capacitor dielectric has a rectifying characteristics. Therefore, when a reverse voltage is applied to it, a large current flows even at a low reverse voltage. As a result, it may spontaneously generate heat and lead to shorting.
- (3) Make sure that the polarity and voltage is correct when applying a multimeter or similar testing instrument to the capacitors because a reverse voltage or overvoltage can be accidentally applied.
- (4) When using the capacitors in a circuit in which a reverse voltage is applied, consult your local Hitachi AIC agent. If the application of an reverse voltage is unavoidable, it must not exceed the following values:

At 25°C: 10% of the rated voltage or 1 V, whichever smaller.

At 85°C: 5% of the rated voltage or 0.5 V, whichever smaller.

Further, the reverse voltage application time must be no longer than 240 hours, with the power supply impedance maintained at 33Ω or more.

\*These limits are reference value.

## 4. Reliability of Tantalum Capacitors

### 4.1 General

The failure rate of the tantalum capacitor varies with the derating ratio, ambient temperature, circuit resistance, circuit application, etc. Therefore, when proper selections are made so as to afford additional margins, higher reliabilities can be derived from the tantalum capacitors. Some examples of actual failure rates are presented below for your reference.

### 4.2 Failure Rate Calculation Formula

The tantalum capacitors are designed to work at their basic failure rates shown in Table 3 that prevail when the rated voltage is applied for 1000 hours at 85°C.

Table 3 Basic failure rate

Type	Classification	Basic failure rate
TMCR	Low ESR type	1%/1000hrs
TMF	Face down terminals	
TMCJ	Ultra small-size type (0603)	
TMCP	Ultra small-size type (0805)	
TMCU	Low profile type	
TMCM	Small type	
TMCS	Standard type	
TMCTX	Fuse-incorporated type	0.5%/1000hrs
TMCH	High-reliability type	
TNC	High performance polymer type	

A capacitor failure rate can be calculated from the formula shown below. Note that a capacitor failure rate can be lowered by giving margins to the circuit temperature, applied voltage ratio (derating factor), and circuit resistance selected for the basic failure rate.

#### • Failure rate calculation formula

$$\lambda_{use} = \lambda_{85} \times K_V \times K_R$$

$\lambda_{use}$ : Estimated capacitor failure rate under the operating conditions.

$\lambda_{85}$ : Basic failure rate (Table 3)

$K_V$ : Failure rate correction coefficient by the ambient temperature and derating factor.

$K_R$ : Failure rate correction coefficient by the circuit resistance, which is the series-connected resistance divided by the voltage applied to the capacitor. This resistance is connected in series when the power supply side is viewed from the capacitor side. The  $K_V$  and  $K_R$  values must be determined according to Figs. 8 and 9.

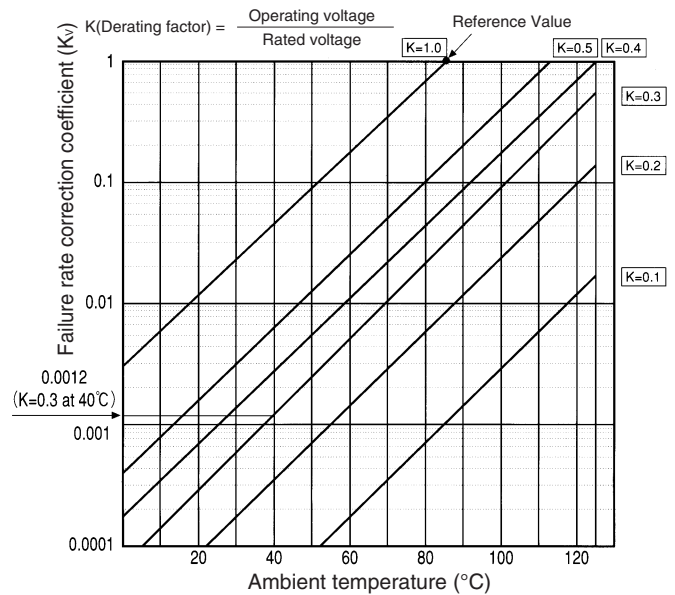


Fig. 8 Ambient temperature and derating-dependent failure rate correction coefficient ( $K_V$ )

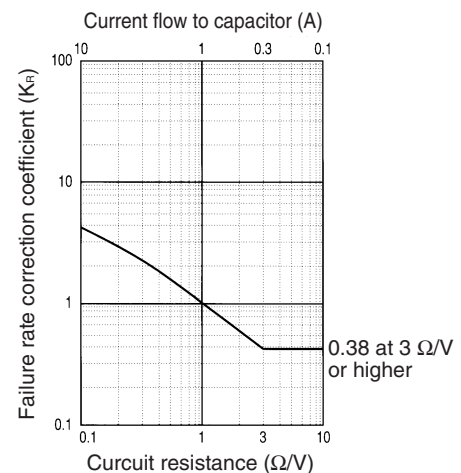


Fig. 9 Circuit resistance-dependent failure rate correction coefficient ( $K_R$ )

### 4.3 Example of Capacitor Failure Rate Calculation

#### • Operating conditions

Type:	TMCM type
Rating:	10 V, 10 μF (B case)
Operating temperature:	40°C
Derating factor:	0.3 [K=operating voltage / rated voltage=3 V/10 V=0.3]
Circuit resistance:	3Ω / V
$\lambda_{85}$ :	1%/1000 hours (from Table 3)
$K_V$ :	0.0012 (from Fig. 8)
$K_R$ :	0.38 (from Fig. 9)

$$\begin{aligned} \lambda_{use} &= \lambda_{85} \times K_V \times K_R = 1\%/1000h \times 0.0012 \times 0.38 \\ &= 1 \times 10^{-6} \times 0.0012 \times 0.38 \\ &= 4.56 \times 10^{-9} \\ &= 0.000456\%/1000h \end{aligned} \quad \left. \vphantom{\begin{aligned} \lambda_{use} &= \lambda_{85} \times K_V \times K_R \\ &= 1 \times 10^{-6} \times 0.0012 \times 0.38 \\ &= 4.56 \times 10^{-9} \\ &= 0.000456\%/1000h \end{aligned}} \right\} \text{Estimated failure rate} = 4.56\text{Fit}$$

## 5. Mounting Precautions

### 5.1 Limit Pressure on Capacitor Installation with Mounter

Pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or the like (maximum permitted pressurization time: 5 seconds). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and/or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

### 5.2 Flux Selection

- (1) Select a flux that contains a minimum of chlorine and amine.
- (2) After flux use, the chlorine and amine in the flux remain must be removed.

### 5.3 Recommended Soldering Pattern Dimensions

The recommended chip soldering pattern dimensions are as shown in Table 4 and Fig. 10. Note, however, that they are affected by such factors as reflow conditions, solder type, and circuit board size.

If the pattern area is significantly larger than the capacitor terminal area, the capacitor in place may be displaced when the solder melts.

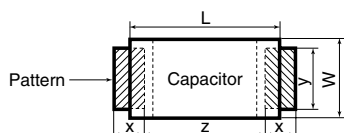


Fig. 10

Table 4 Recommended soldering pattern dimensions (mm)

Dimensions Case	Capacitor size		Pattern dimensions		
	L	W	x	y	z
LM	1.6	0.8	0.5 <sup>MIN</sup>	0.65 <sup>MIN</sup>	0.65 <sup>MAX</sup>
J	1.6	0.8	0.9	1.0	0.7
LP	2.0	1.25	0.5 <sup>MIN</sup>	0.8 <sup>MIN</sup>	1.05 <sup>MAX</sup>
P	2.0	1.25	1.2	1.1	0.8
LA	3.2	1.6	0.8 <sup>MIN</sup>	1.2 <sup>MIN</sup>	1.65 <sup>MAX</sup>
LA,UA,A	3.2	1.6	1.6	1.2	1.2
UB,B	3.5	2.8	1.6	2.2	1.4
C	5.8	3.2	2.3	2.4	2.4
E	7.3	4.3	2.3	2.6	3.8
F	7.3	5.8	2.3	3.8	3.8

### 5.4 Chip Soldering Temperature and Time

For the capacitor body, the chip soldering temperature and time must be as shown below.

- (1) Reflow soldering (infrared, hot air, hot plate)  
Capacitor body temperature: 260°C or lower (TNC:240°C or lower)  
Time: 10 sec. max.  
Permitted temperature/time range: See Fig. 11.

NOTE 1: When upward heating is provided by infrared, the capacitor body temperature rises above the circuit board surface temperature.

When a high-power hot blast stove or the like is used, a sudden temperature rise occurs.

Therefore, a 130-160°C, 1-minute preheating zone should be provided to ensure that the difference from the reflow maximum temperature is not greater than 100°C (see Fig. 12).

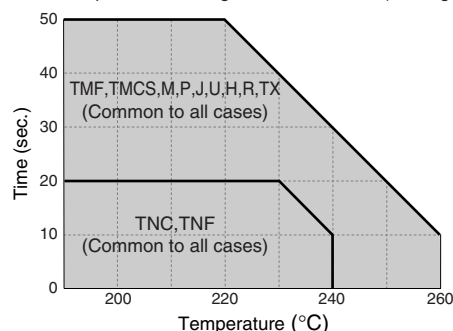


Fig. 11 Reflow soldering permitted temperature / time range

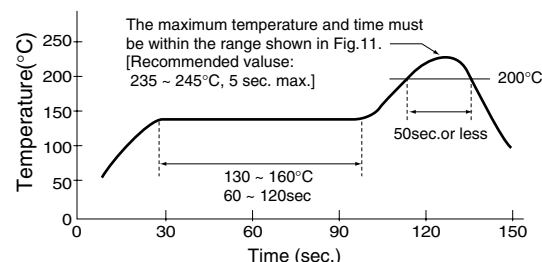


Fig. 12 Recommended temperature profile

- (2) Flow soldering (not available for TNC type)  
Solder bath temperature: 260°C or lower  
Time: LM, J, LP, P, UA, LA, A, UB, or B case, 10 sec max. C, E, F case, 5 sec max.

Permitted temperature and time range: See Fig. 13.

NOTE 1: To avoid sudden heating, conduct preheating. 130-160°C, 1-minute preheating zone should be provided (see Fig. 14).

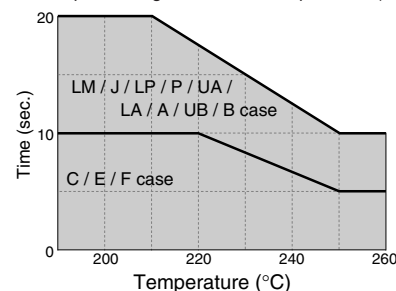


Fig. 13 Flow soldering permitted temperature / time range

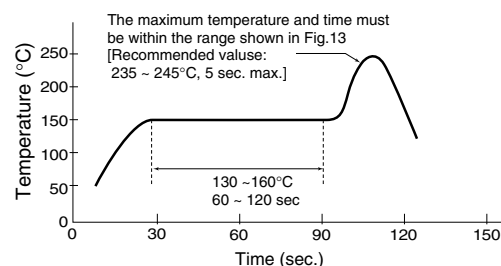


Fig. 14 Recommended temperature profile

- (3) Soldering with a soldering iron  
The use of a soldering iron should be avoided wherever possible. If it is unavoidable, follow the instructions set forth in Table 5.  
The time of soldering with an iron should be one.

Table 5

Type	TMCR, TMCS, TMCM, TMCP, TM CJ, TMCU, TMCH	TMCTX *
Soldering-iron tip temperature	350°C MAX	290°C MAX
Time	3 sec MAX	3 sec MAX
Soldering-iron power	30 W MAX	30 W MAX

\*If a soldering iron is used at a high temperature for the TMCTX type which incorporates a thermal fuse, the fuse opens. Due care must be used to avoid such a trouble.

\*If a soldering iron needs to be used for TMF and/or TNC type, please contact us for information.

- (4) Repetition of soldering  
The soldering conditions for soldering operations (1) through (3) above are established on the presumption that only one type of soldering operation is conducted. When repeating a reflow soldering or a combined flow-and-reflow soldering operation, comply with the following conditions:
  - i) Once the capacitor is mounted, it must not be removed for reuse.
  - ii) Any type of soldering operation may be performed to the capacitor only twice.
  - iii) The second performance of a type of soldering operation must not be initiated until a 2-hour or longer heat dissipation period has elapsed after completion of the first performance.
  - iv) Cleaning must be conducted upon completion of the second performance.

\*Soldering conditions (temperature, time) of Sn 100 terminal products are same as the above.

## 12



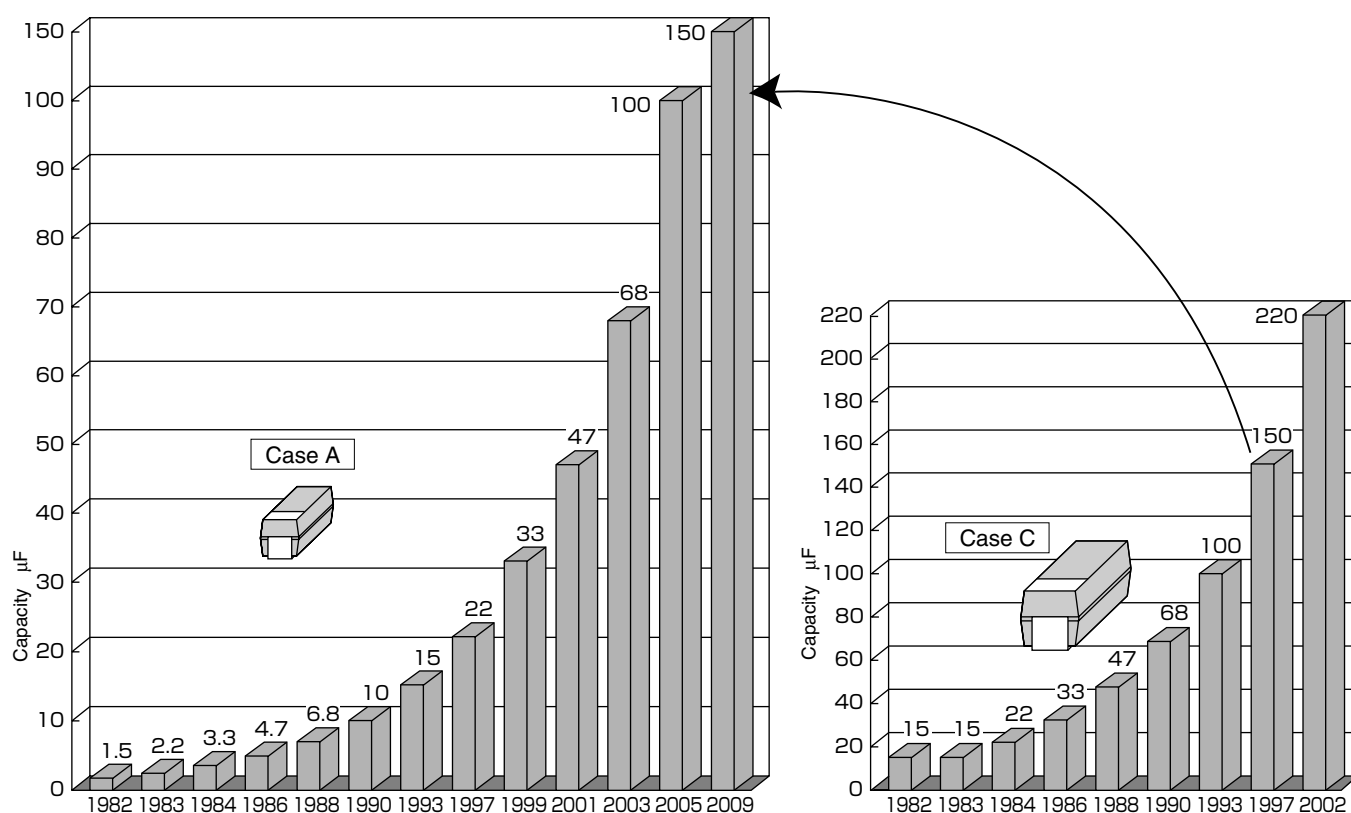
## About downsizing (upgrading)

To meet the recent needs for electronic products smaller in size and lighter in weight, chip type tantalum capacitor manufacturers have been downsized their products by various methods. Of these methods, the method of ensuring a required capacity by thinning the dielectric film greatly reduces the withstand voltage characteristics. The most common method is therefore by using fine tantalum powder to enlarge the surface area of the anode per unit area.

The TMC type has been enlarged in capacity and reduced in size by taking full advantage of fine powder (hereinafter referred to as "high-CV powder"). In recent years, however, technical advances have been remarkable in downsizing and capacity expansion in the industry of multilayer ceramic capacitors. The advantage of TMCs is therefore being challenged. To keep the advantage in competing with ceramic capacitors today, it is imperative to use high-CV powder to upgrade the TMCs.

Hitachi AIC is planning to make yet another family of products.

- (1) Development of products with a larger capacity than the TMCM type
- (2) Development of products with a larger capacity than the TMCP type (0805 inch)
- (3) Development of products with a larger capacity than the TMCU type (thin type, a low-height version of the TMCM type).
- (4) Development of products TMCJ type (0603 inch)
- (5) Development of products Niobium solid Electrolytic Capacitors.
- (6) Development of products with a larger capacity than the TMF type (Face down terminals type).



History of capacity expansion in 6.3-V(7V) models

## Pb free chip tantalum Capacitor (TMC serie)

### •Tin-based Solder for Terminal Plating – Heat-resistant at up to 260°C

#### Lead alloy solder mounting

No need to change existing mounting conditions (for conventional – with lead – production lines)

#### Lead-free solder mounting

For lead-free solder of any base materials (For lead-free production lines)

Hitachi AIC has developed a tantalum capacitor containing no lead at the terminal, which went into mass production in April 2001.

Lead alloy has long been used in electrical and electronic equipment for solderings. Lead is, however, known to be harmful. The European Union has announced that it would ban the use of lead and other hazardous substances from 2006.

In the interest of preserving the global environment, Hitachi AIC has been studying a way to eliminate the use of lead in terminal plating.

The new plating method is based on tin, the main ingredient in joint solder. It can therefore be used in both lead alloy and lead-free soldering.

We ensure this product's high degree of heat-resistance (260°C ; up to 10 seconds) to provide strong support in the move to lead-free production lines.

# TANTALUM ELECTROLYTIC CAPACITORS

## Specifications Table

	TNF	TNC	TMF	TMCJ	TMCS	Test conditions JIS C5101-1:1998
Specifications Table	-55℃～+105℃	-55℃～+105℃	-55℃～+125℃	-55℃～+125℃	-55℃～+125℃	
Rated voltage	DC2.5～10V	DC2.5～10V	DC2.5～16V	DC2.5～20V	DC4～35V	85℃
Surge voltage	DC3～13V	DC3～13V	DC3.2～20V	DC3.2～26V	DC5～45V	85℃
Derated voltage	DC1.6～6.3V	DC1.6～6.3V (105℃)	DC1.6～10V	DC1.6～13V	DC2.5～22V	125℃ (TNC:105℃, THC:150℃)
Capacitance	10～100 μ F	3.3～330 μ F	2.2～220 μ F	0.68～22 μ F	0.1～68 μ F	
Capacitance tolerance	±20%	±20%	±20%	±20%	±10% or 20%	Paragraph 4.7, 120 Hz
Leakage current	Refer to standard product table	Refer to standard product table	0.01CV or 0.5 μ A, whichever is larger or less.	Refer to standard product table	0.01CV or 0.5 μ A, whichever is larger or less.	Paragraph 4.9, in 5 minutes after the rated voltage is applied.
tan δ	0.1 or less	0.1 or less	0.3 or less	0.2 or less	0.1～1.0 1.5～68 0.04 or less 0.06 or less	Paragraph 4.8, 120 Hz
ESR	LP case 200mΩ, 500mΩ <sup>MAX</sup> LA case 200mΩ, 500mΩ <sup>MAX</sup>	—	—	—	—	—
Surge withstanding voltage	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±5% or less	Paragraph 4.26
	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	
	LC 300% or less Specified initial value or less	LC ≤0.1CV or ≤0.3CV	LC Specified initial value or less	LC Specified initial value or less	LC Specified initial value or less	
Temperature characteristics						Paragraph 4.24
Solder heat resistance	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±5% or less	Solder Dip 260±5℃ LM,J,LP,P,LA, C,E,F case UA,A,UB,B case 10±1 sec. 5±0.5 sec. Reflow 260℃ 10±1 sec.
	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	
	LC 300% or less Specified initial value or less	LC ≤0.1CV or ≤0.3CV	LC Specified initial value or less	LC Specified initial value or less	LC Specified initial value or less	
Moisture resistance no load	ΔC/C +30%～-20% or less	ΔC/C +30%～-20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±5% or less	Paragraph 4.22 40℃ 90～95%RH, 500hours (TMCH,THC:85℃, 85%RH, 1000hours)
	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ 150% or less Specified initial value or less	tan δ 150% or less Specified initial value or less	tan δ Specified initial value or less	
	LC 300% or less Specified initial value or less	LC 300% or less Specified initial value or less	LC Specified initial value or less	LC Specified initial value or less	LC Specified initial value or less	
High-temperature load	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±10% or less	Paragraph 4.23 85℃ The rated voltage is applied for 2000 hours. (TMCH:Derated voltage in 125℃, THC:Derated voltage in 150℃)
	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	
	LC 300% or less Specified initial value or less	LC 300% or less Specified initial value or less	LC 200% or less Specified initial value or less	LC 200% or less Specified initial value or less	LC 125% or less Specified initial value or less	
Thermal shock	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±20% or less	ΔC/C ±5% or less	Leave at -55℃, normal temperature, 125℃, and normal temperature for 30 min., 3 min., 30 min., and 3 min. Repeat this operation 5 cycles running. TMCS,TMCTX:20 cycles TMCH,THC:1000 cycles
	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	tan δ Specified initial value or less	
	LC 300% or less Specified initial value or less	LC ≤0.1CV or ≤0.3CV	LC Specified initial value or less	LC Specified initial value or less	LC Specified initial value or less	
Moisture resistance load	—	—	—	—	ΔC/C ±10% or less	40℃, humidity 90 to 95%RH The rated voltage is applied for 500 hours. (TMCH,THC:65℃)
					tan δ 150% or less Specified initial value or less	
					LC 125% or less Specified initial value or less	
Failure rate	1%／1000hrs	1%／1000hrs	The same as shown at left	The same as shown at left	The same as shown at left	85℃. The rated voltage is applied (through a protective resistor of 1Ω/V).

※ This catalog is designed for providing general information. Please inquire of our Sales Department to confirm specifications prior to use.

# TANTALUM ELECTROLYTIC CAPACITORS

	TMCM				TMCP				TMCU				TMCR				Test conditions JIS C5101-1:1998			
Specifications Table	-55℃～+125℃				The same as shown at left				The same as shown at left				The same as shown at left							
Rated voltage	DC2.5～35V				DC2.5～25V				DC2.5～35V				DC6.3～35V				85℃			
Surge voltage	DC3.2～45V				DC3.2～32V				DC3.2～45V				DC8～45V				85℃			
Derated voltage	DC1.6～22V				DC1.6～16V				DC1.6～22V				DC4～22V				125℃ (TNC:105℃, THC:150℃)			
Capacitance	0.47～470 μ F				0.1～47 μ F				0.1～220 μ F				10～330 μ F							
Capacitance tolerance	±10% or 20%				The same as shown at left				The same as shown at left				The same as shown at left				Paragraph 4.7, 120 Hz			
Leakage current	Refer to standard product table				Refer to standard product table				Refer to standard product table				0.01CV or less				Paragraph 4.9, in 5 minutes after the rated voltage is applied.			
tanδ	Refer to standard product table				Refer to standard product table				Refer to standard product table				10～68 100～150 220 330 0.06 or less 0.08 or less 0.1 or less 0.15 or less				Paragraph 4.8, 120 Hz			
Surge withstanding voltage	△C/C ±5% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±20% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±5% or less tan δ Specified initial value or less LC Specified initial value or less				The same as shown at left				Paragraph 4.26			
Temperature characteristics		Specified initial value	-55	85	125		Specified initial value	-55	85	125		Specified initial value	-55	85	125		Specified initial value	-55	85	125
	△C/C	—	-10～0%	0～+10%	0～+12%	△C/C	—	-20～0%	0～+20%	0～+20%	△C/C	—	-10～0%	0～+10%	0～+12%	△C/C	—	-10～0%	0～+10%	0～+12%
	tan δ	0.04 0.06	0.09 0.1	0.07 0.08	0.09 0.1	tan δ	0.06 0.08	0.1 0.12	0.08 0.1	0.1 0.12	tan δ	0.04 0.06	0.05 0.08	0.04 0.06	0.05 0.06	tan δ	0.06 0.08	0.1 0.12	0.08 0.1	0.1 0.12
	Value shown	0.1	0.14	0.12	0.14	Value shown	0.1	0.14	0.12	0.14	Value shown	0.1	0.14	0.12	0.14	Value shown	0.1	0.14	0.12	0.14
	table	0.12	0.16	0.14	0.16	table	0.12	0.16	0.14	0.16	table	0.1	0.14	0.12	0.14	table	0.1	0.14	0.12	0.14
	or less	0.16	0.20	0.18	0.20	or less	0.12	0.16	0.14	0.16	or less	0.12	0.16	0.14	0.16	or less	0.15	0.22	0.18	0.22
		0.18	0.34	0.20	0.22		0.20	0.24	0.22	0.24		0.18	0.22	0.20	0.22		0.30	0.60	0.30	0.40
		0.20	0.36	0.22	0.24		0.30	0.60	0.30	0.40		0.20	0.24	0.22	0.24		0.30	0.60	0.30	0.40
		0.30	0.60	0.30	0.40		0.30	0.60	0.30	0.40		0.20	0.24	0.22	0.24		0.30	0.60	0.30	0.40
		LC	Refer to standard product table	—	1000% or less specified initial value or less	1250% or less specified initial value or less	LC	Refer to standard product table	—	1000% or less specified initial value or less	1250% or less specified initial value or less	LC	Refer to standard product table	—	1000% or less specified initial value or less	1250% or less specified initial value or less	LC	0.01CV	—	0.1CV
Solder heat resistance	△C/C ±5% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±20% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±5% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				Solder Dip LM,J,LP,P,LA, UA,A,UB,B case 10±1 sec. Reflow 260℃ 260±5℃ C,E,F case 5±0.5 sec. 10±1 sec.			
Moisture resistance no load	△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±20% or less tan δ 150% or less Specified initial value or less LC Specified initial value or less				△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				Paragraph 4.22 40℃ 90 ～ 95%RH, 500hours (TMCH,THC:85℃,85%RH, 1000hours)			
High-temperature load	△C/C ±10% or less tan δ Specified initial value or less LC 125% or less Specified initial value or less				△C/C ±20% or less tan δ Specified initial value or less LC 200% or less Specified initial value or less				△C/C ±10% or less tan δ Specified initial value or less LC 125% or less Specified initial value or less				△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				Paragraph 4.23 85℃ The rated voltage is applied for 2000 hours (TMCH:Derated voltage in 125℃, THC:Derated voltage in 150℃)			
Thermal shock	△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±20% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±5% or less tan δ Specified initial value or less LC Specified initial value or less				△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				Leave at -55℃, normal temperature, 125℃, and normal temperature for 30 min., 3 min., 30 min., and 3 min. Repeat this operation 5 cycles running TMCS,TMCTX:20 cycles TMCH,THC:1000 cycles			
Moisture resistance load	△C/C ±10% or less tan δ 150% or less Specified initial value or less LC 200% or less Specified initial value or less				△C/C ±20% or less tan δ 150% or less Specified initial value or less LC 200% or less Specified initial value or less				△C/C ±10% or less tan δ 150% or less Specified initial value or less LC 200% or less Specified initial value or less				△C/C ±10% or less tan δ Specified initial value or less LC Specified initial value or less				40℃, humidity 90 to 95%RH The rated voltage is applied for 500 hours (TMCH,THC:65℃)			
Failure rate	1%／1000hrs				The same as shown at left				The same as shown at left				The same as shown at left				85℃. The rated voltage is applied (through a protective resistor of 1Ω/V).			

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# TANTALUM ELECTROLYTIC CAPACITORS

## Specifications Table

	TMCH					TMCTX					THC					Test conditions JIS C5101-1:1998	
Specifications Table	-55℃～+125℃					The same as shown at left					-55℃～+150℃						
Rated voltage	DC4～35V					DC10～35V					DC10～35V					85℃	
Surge voltage	DC5～45V					DC13～45V					DC13～45V					85℃	
Derated voltage	DC2.5～22V					DC6.3～22V					DC6.3～22V					125℃ (TNC:105℃, THC:150℃)	
Capacitance	0.1～100 μ F					1～68 μ F					0.33～47 μ F						
Capacitance tolerance	±10% or 20%					The same as shown at left					The same as shown at left					Paragraph 4.7, 120 Hz	
Leakage current	0.005 CV or 0.25 μ A, whichever is larger or less					0.01 CV or 0.5 μ A, whichever is larger or less					0.05 CV or 0.25 μ A, whichever is larger or less					Paragraph 4.9, in 5 minutes after the rated voltage is applied.	
tanδ	0.1～1.0		0.04 or less			1.0 or less		0.04 or less			1.0 or less		0.04 or less			Paragraph 4.8, 120 Hz	
	1.5～100		0.06 or less			1.5～22		0.05 or less			1.5 or more		0.06 or less				
Surge withstanding voltage	ΔC/C    ±5% or less tan δ    Specified initial value or less LC       Specified initial value or less					The same as shown at left					ΔC/C    ±10% or less tan δ    Specified initial value or less LC       Specified initial value or less					Paragraph 4.26	
Temperature characteristics		Specified initial value	-55	85	125		Specified initial value	-55	85	125		Specified initial value	-55	105	150	Paragraph 4.24	
	ΔC/C	—	-10～0%	0～+10%	0～+12%	ΔC/C	—	-10～0%	0～+10%	0～+12%	ΔC/C	—	-10～0%	0～+10%	0～+20%		
	tan δ	0.04	0.04	0.05	0.05	tan δ	0.04	0.09	0.07	0.09	tan δ	0.04	0.04	0.06	0.08		
	Value shown	0.06	0.06	0.07	0.07	Value shown	0.05	0.1	0.08	0.1	Value shown	0.06	0.06	0.08	0.1		
	table	0.08	0.08	0.10	0.12	table	0.06	0.12	0.1	0.12	table						
	or less					or less					or less						
LC	0.005CV or 0.25 μA or less	—	0.05CV or 2.5 μA or less	0.062CV or 3.12 μA or less	LC	0.01CV or 0.5 μA or less	—	0.1 CV or 5 μA or less	0.125CV or 6.25 μA or less	LC	0.005CV or 0.25 μA or less	—	0.1 CV or 5 μA or less	0.125CV or 6.25 μA or less			
Solder heat resistance	ΔC/C    ±5% or less tan δ    Specified initial value or less LC       Specified initial value or less					The same as shown at left					ΔC/C    ±5% or less tan δ    Specified initial value or less LC       Specified initial value or less					Solder Dip            260±5℃ LM,J,LP,P,LA,       C,E,F case UA,A,UB,B case 10±1 sec.            5±0.5 sec. Reflow 260℃       10±1 sec.	
Moisture resistance no load	ΔC/C    ±5% or less tan δ    150% or less Specified initial value or less LC       200% or less Specified initial value or less					ΔC/C    ±10% or less tan δ    Specified initial value or less LC       Specified initial value or less					ΔC/C    ±10% or less tan δ    150% or less Specified initial value or less LC       200% or less Specified initial value or less					Paragraph 4.22    40℃ 90 ～ 95%RH, 500h (TMCH,THC:85℃,85%RH, 1000hours)	
High-temperature load	ΔC/C    ±10% or less tan δ    Specified initial value or less LC       125% or less Specified initial value or less					The same as shown at left					The same as shown at left					Paragraph 4.23    85℃ The rated voltage is applied for 2000 hours. (TMCH:Derated voltage in 125℃, THC:Derated voltage in 150℃)	
Thermal shock	ΔC/C    ±5% or less tan δ    Specified initial value or less LC       200% or less Specified initial value or less					ΔC/C    ±10% or less tan δ    Specified initial value or less LC       Specified initial value or less					ΔC/C    ±10% or less tan δ    Specified initial value or less LC       200% or less Specified initial value or less					Leave at -55℃, normal temperature, 125℃, and normal temperature for 30 min., 3 min., 30 min., and 3 min. Repeat this operation 5 cycles running. TMCS,TMCTX:20 cycles TMCH,THC:1000 cycles	
Moisture resistance load	ΔC/C    ±5% or less tan δ    150% or less Specified initial value or less LC       200% or less Specified initial value or less					ΔC/C    ±10% or less tan δ    150% or less Specified initial value or less LC       200% or less Specified initial value or less					ΔC/C    ±10% or less tan δ    150% or less Specified initial value or less LC       200% or less Specified initial value or less					40℃, humidity 90 to 95%RH The rated voltage is applied for 500 hours. (TMCH,THC:65℃)	
Failure rate	0.5%/1000hrs					1%/1000hrs					0.5%/1000hrs					85℃. The rated voltage is applied (through a protective resistor of 1 Ω/V).	

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